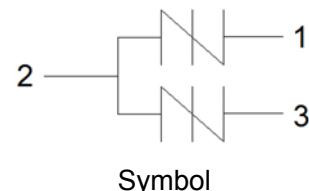


**DESCRIPTION:**

PxxxxSDT-3L series are a type of semiconductor components. They can be used to replace the traditional GDT and TVS combination solution RS485, they have small dimension, low capacitance etc.



SMC-3

**FEATURES:**

- ✧ Glass passivated junction.
- ✧ Excellent capability of absorbing transient surge.
- ✧ Quick response to surge voltage (ns Level).
- ✧ Eliminates overvoltage caused by fast rising transients.
- ✧ Lead free in compliance with EU RoHS 2011/65/EU directive
- ✧ Moisture sensitivity level: Level 1.
- ✧ Non degenerative.

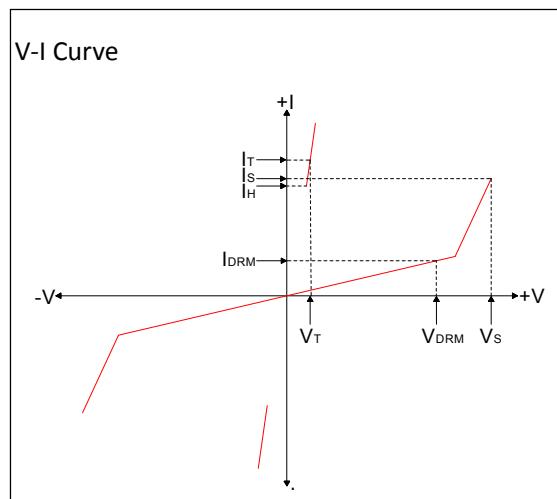
ABSOLUTE MAXIMUM RATINGS($T_A=25^\circ\text{C}$, RH=45%-75%, unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|---|--------------------------------|-------------|------------------|
| Storage temperature range | T_{STG} | -60 to +150 | $^\circ\text{C}$ |
| Operating junction temperature range | T_J | -40 to +125 | $^\circ\text{C}$ |
| Operating ambient temperature range | T_A | -40 to +125 | $^\circ\text{C}$ |
| Peak pulse current@1.2/50 μs -8/20 μs @2 Ω (Note 1) | $I_{PP}@T_A=25^\circ\text{C}$ | 3000(+15%) | A |
| | $I_{PP}@T_A=105^\circ\text{C}$ | 3000(+15%) | A |

Notes: 1. Surge rating: 3000A@1.2/50 μs -8/20 μs @2 Ω (PIN 1 or 3 to 2)

ELECTRICAL CHARACTERISTICS($T_A=25^\circ\text{C}$)

| Symbol | Parameter |
|-----------|------------------------|
| V_{DRM} | Peak off-state voltage |
| I_{DRM} | Off-state current |
| V_s | Switching voltage |
| I_s | Switching current |
| V_T | On-state voltage |
| I_T | On-state current |
| I_H | Holding current |
| C_O | Off-state capacitance |



MARKING

P08T: Device Marking Code
2009: In ninth week, 2020

ELECTRICAL CHARACTERISTICS($T_A=25^\circ\text{C}$, continued)

| Part Number | $I_{DRM}@V_{DRM}$ | | $V_s^{①}@I_s$ | | $V_T@I_T$ | | I_H | $C_o^{②}$ | | Marking | |
|-------------|-------------------|-----------|---------------|-----|-----------|-----|-------|-----------|-----|---------|--|
| | μA | V | V | mA | V | A | mA | pF | | | |
| | max | Pin 1,3-2 | Pin 1,3-2 | max | max | max | min | min | max | | |
| P0080SDT-3L | 5 | 6 | 15 | 800 | 4 | 2.2 | 50 | 400 | 700 | P08T | |
| P0150SDT-3L | 5 | 15 | 25 | 800 | 4 | 2.2 | 50 | 100 | 400 | P15T | |

ELECTRICAL CHARACTERISTICS($T_A=125^\circ\text{C}$, continued)

| Part Number | $I_{DRM}@V_{DRM}$ | | $V_s^{①}@I_s$ | | $V_T@I_T$ | | I_H | $C_o^{②}$ | | Marking | |
|-------------|-------------------|-----------|---------------|-----|-----------|-----|-------|-----------|-----|---------|--|
| | μA | V | V | mA | V | A | mA | pF | | | |
| | max | Pin 1,3-2 | Pin 1,3-2 | max | max | max | min | min | max | | |
| P0080SDT-3L | 20 | 6 | 15 | 800 | 4 | 2.2 | 35 | 400 | 700 | P08T | |
| P0150SDT-3L | 20 | 15 | 25 | 800 | 4 | 2.2 | 35 | 100 | 400 | P15T | |

① V_s is measured at 100KV/s

② Off-state capacitance is measured in $V_{DC}=2\text{V}, V_{RMS}=1\text{V}, f=1\text{MHz}$

ORDERING INFORMATION

| | | | | | |
|-------------------------|----------------|-----------------|---|----|---------------------|
| P | 008 | 0 | S | DT | -3L |
| Series code P: SIDAC | | | | | 3 Pins |
| | Median voltage | | | | Surge ratings:3000A |
| | | 0: Bi-direction | | | Package type:SMC-3 |

SOLDERING PARAMETERS

| Reflow Condition | | Pb-Free assembly (see FIG.2) |
|---|------------------------------------|---------------------------------|
| Pre Heat | -Temperature Min ($T_{s(\min)}$) | +150°C |
| | -Temperature Max($T_{s(\max)}$) | +200°C |
| | -Time (Min to Max) (t_s) | 60-180 secs. |
| Average ramp up rate (Liquidus Temp (T_L)to peak) | | 3°C/sec. Max |
| $T_{s(\max)}$ to T_L - Ramp-up Rate | | 3°C/sec. Max |
| Reflow | -Temperature(T_L) (Liquidus) | +217°C |
| | -Temperature(t_L) | 60-150 secs. |
| Peak Temp (T_p) | | +260(+0/-5)°C |
| Time within 5°C of actual Peak Temp (t_p) | | 30 secs. Max |
| Ramp-down Rate | | 6°C/sec. Max |
| Time 25°C to Peak Temp (T_P) | | 8 min. Max |
| Do not exceed | | +260°C |

FIG.1: Pulse waveform

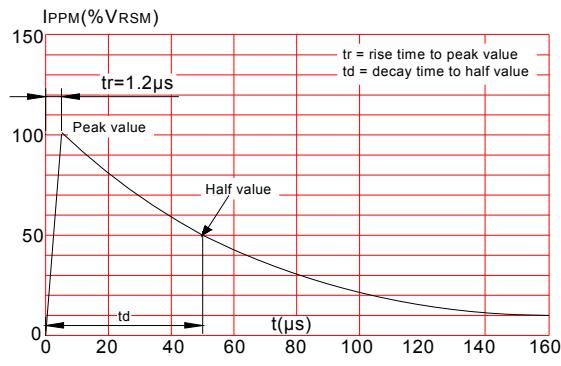


FIG.3: Normalized Vs change vs. junction temperature

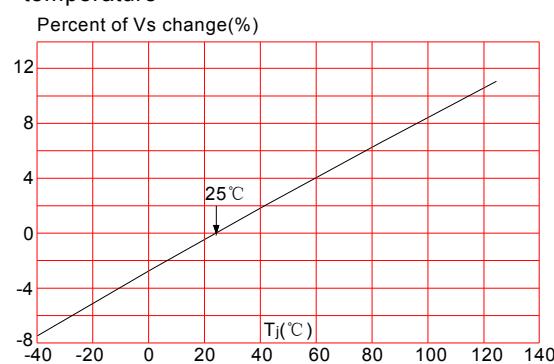


FIG.2: Reflow condition

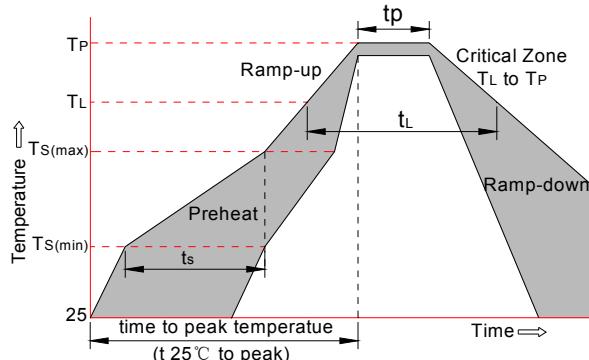
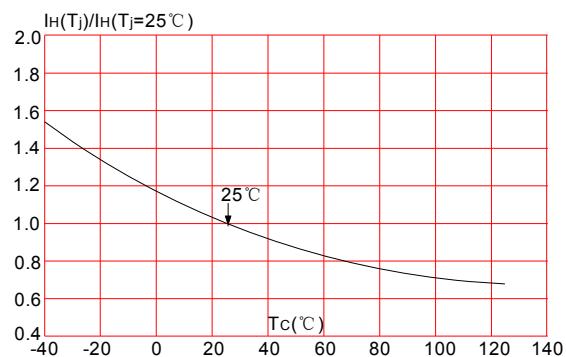
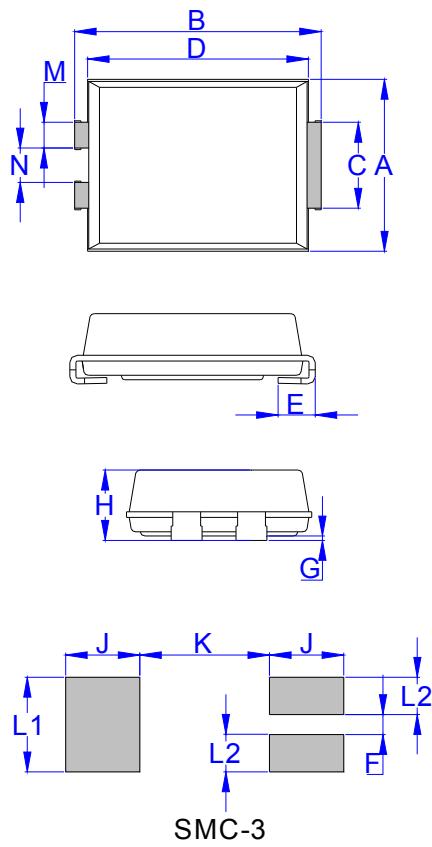


FIG.4: Normalized DC holding current vs. case temperature

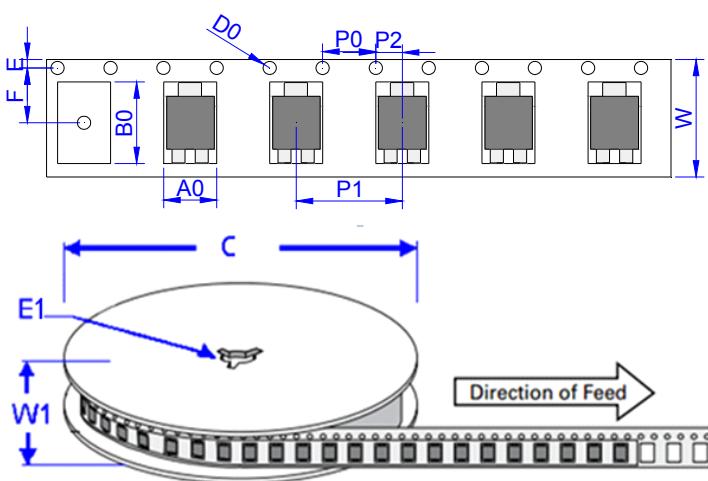


PACKAGE MECHANICAL DATA



| Ref. | Dimensions | | | |
|------|-------------|------|--------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 5.75 | 6.25 | 0.226 | 0.246 |
| B | 7.70 | 8.20 | 0.303 | 0.323 |
| C | 2.75 | 3.25 | 0.108 | 0.128 |
| D | 6.90 | 7.40 | 0.272 | 0.291 |
| E | 0.95 | 1.52 | 0.037 | 0.060 |
| G | - | 0.30 | - | 0.012 |
| H | 2.15 | 2.62 | 0.085 | 0.103 |
| M | 0.70 | 1.10 | 0.028 | 0.043 |
| N | 1.00 | 1.40 | 0.039 | 0.055 |
| L2 | 1.30 | | 0.051 | |
| F | 0.70 | | 0.028 | |
| J | 2.40 | | 0.094 | |
| K | | 4.20 | | 0.165 |
| L1 | 3.30 | | 0.130 | |

TAPE AND REEL SPECIFICATION-SMC-3



| Ref. | Dimensions | |
|------|-------------|----------------|
| | Millimeters | Inches |
| A0 | 6.05 ± 0.3 | 0.238 ± 0.012 |
| B0 | 8.31 ± 0.3 | 0.327 ± 0.012 |
| C | 330.0 | 13.0 |
| D0 | 1.55 ± 0.1 | 0.061 ± 0.004 |
| E | 1.75 ± 0.2 | 0.069 ± 0.008 |
| E1 | 13.3 ± 0.3 | 0.524 ± 0.012 |
| F | 7.50 ± 0.2 | 0.295 ± 0.008 |
| P0 | 4.00 ± 0.2 | 0.157 ± 0.008 |
| P1 | 8.00 ± 0.2 | 0.3145 ± 0.008 |
| P2 | 2.00 ± 0.2 | 0.079 ± 0.008 |
| W | 16.0 ± 0.2 | 0.630 ± 0.008 |
| W1 | 19.7 ± 2.0 | 0.776 ± 0.079 |

| PART No. | UNIT WEIGHT (g/PCS) typ. | REEL (PCS) | PER CARTON (PCS) | DESCRIPTION |
|-------------|-----------------------------|---------------|---------------------|-------------------|
| PxxxxSDT-3L | 0.33 | 3,000 | 48,000 | 13 inch reel pack |

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